Manipulation of cold atoms with the MuQuans laser system

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Introduction

= Motivations

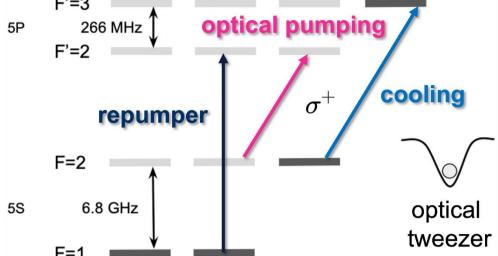
- Atom cooling and trapping
 - Qubit state preparation
 - Non-destructive imaging (NDI)
- Single atoms in array of tweezers
 - Ultrafast regime
 - Rydberg excitation

Cold ⁸⁷*Rb* cloud Manipulation MOT cooling

Laser beams

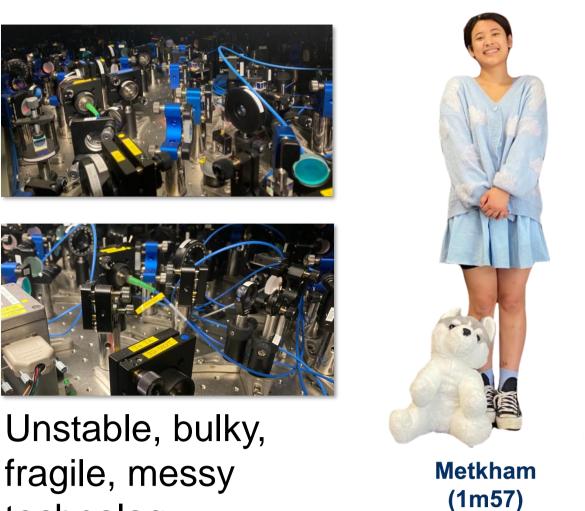
- Cooling on $F=2 \rightarrow F'=3$
- Optical pumping on $F=2 \rightarrow$ F'=2 along with a

repumper on $F=1 \rightarrow F'=2$



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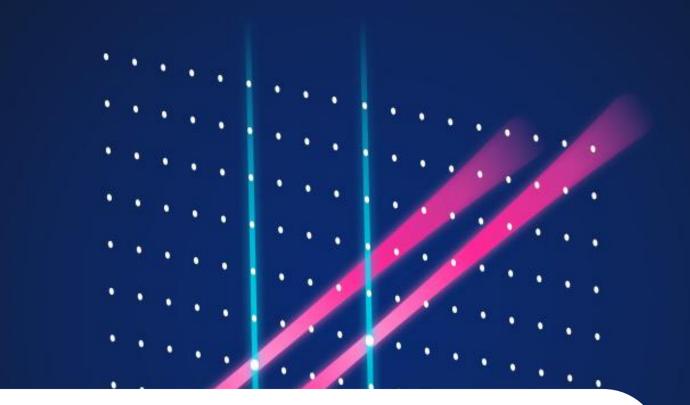
overview = After Before



Intelligent Laser System (ILS) **3D optics 2D optics** LE **EDFA** DDS



大規模・高コヒーレンスな 動的原子アレー型 誤り耐性量子コンピュータ



_ moonshot

- Precise control of the laser amplitude, phase, absolute frequency with fast tunability
- Based on C-band fibered telecom optical components

Robust and reliable technology

. $m_F = 0$ 2



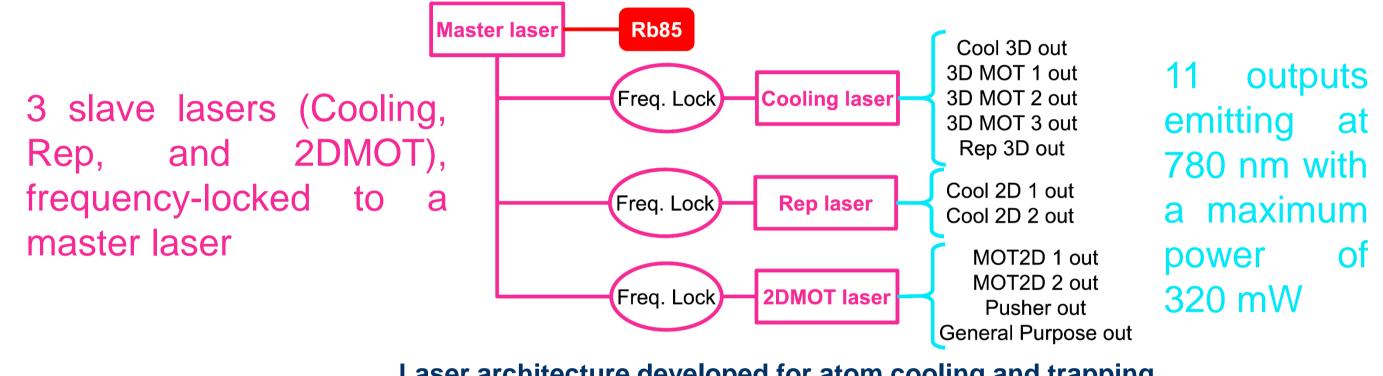


The ILS780-216

Inside the MuQuans Laser

Configuration

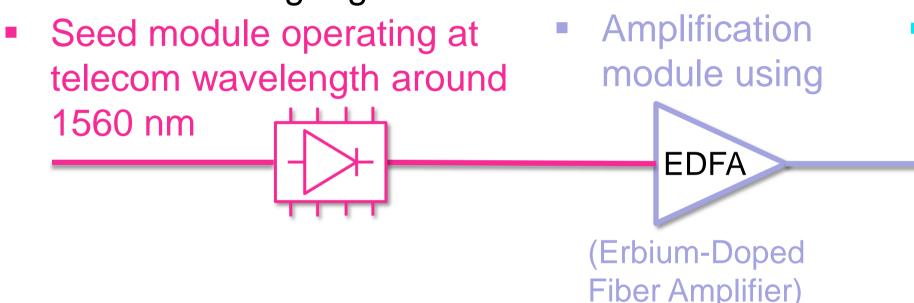
4 independent frequency-stabilized laser heads operating at 780 nm



Laser architecture developed for atom cooling and trapping

Fibered telecom optical components

780 nm wavelength generation with



Frequency doubling module using



(Periodically Poled) Lithium Niobate)

Optical characteristics

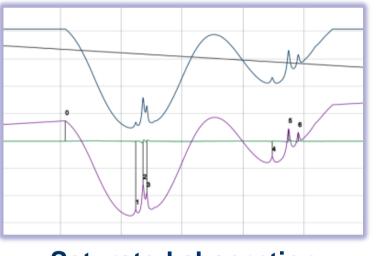
Operating wavelength Output power **Power stability** Linewidth **Tunability range** Sweeping rate **Polarization Beam quality Rise/fall time**

780.23 nm 300 mW per laser head 1% rms over 1 hour < 200 kHz FWHM Up to 1 GHz 250 MHz/ms typ. Linear, PER>20 dB *TEM*₀₀ M2<1.1 < 1 µs

Electrical characteristics

100-110 V Supply voltage **Supply frequency** 50-60 Hz **Electrical power** < 250 W consumption Current < 4 A Air cooling

- Frequency-stabilization module
 - Master laser locked on Rb85 using saturated absorption spectroscopy
 - Beat notes sent to PLL with reference frequencies provided by the DDS rack

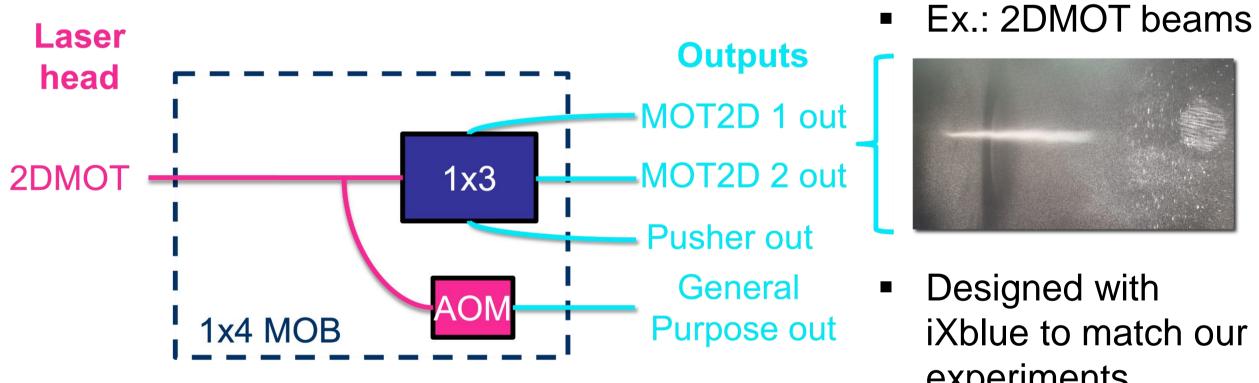


Only suitable for ${}^{87}Rb$, but not for other cold-atom experiments due to the limited wavelength range of Er-doped technology

Saturated absorption spectroscopy

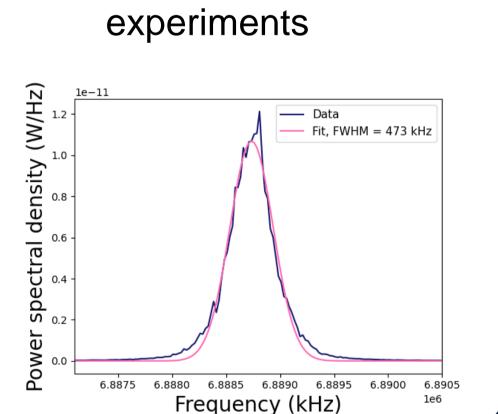
Implementation

Micro optical bench



Laser linewidth

- Linewidth estimated from a beat note between two different laser outputs
- Phase coherence between two beams to drive Raman transitions
- Linewidth FWHM = 473 kHz

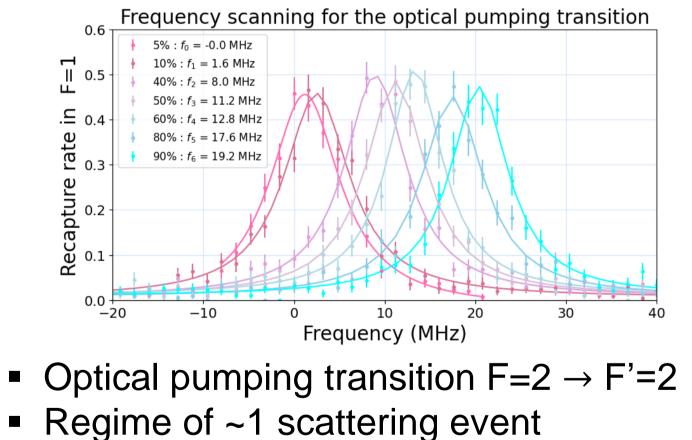


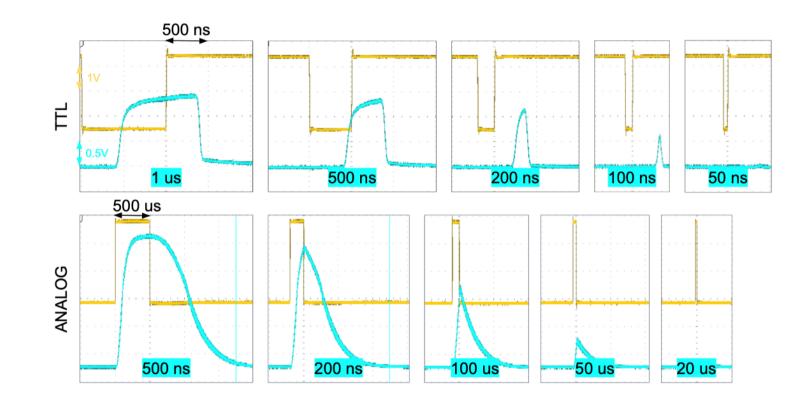
Tunability

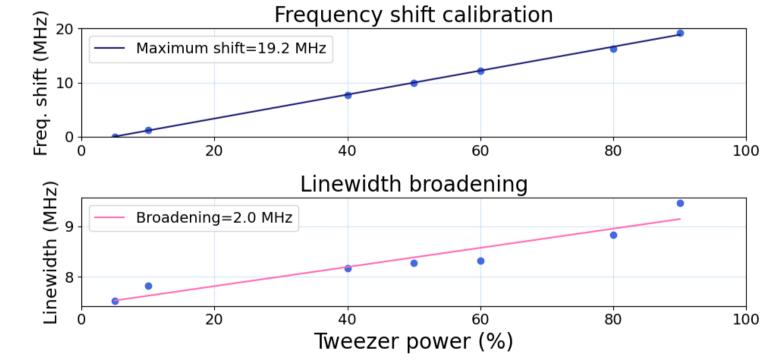
Intensity modulation

- MuQuans AOM as power modulators and active switches
- TTL output with faster response time (~100 ns) than analog output (~1 ms)
- Extinction ratio : 57.8 dBm

Frequency tunability



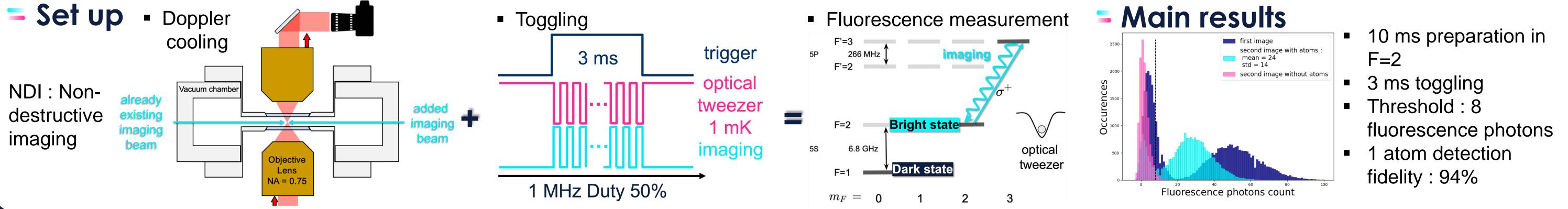




- Trap inhomogeneity
- Not a perfect single-photon scattering event

Towards ND

\wedge



Conclusion

- Abilities

✓ Dedicated system to atom cooling, state preparation and, measurement

Cold atoms manipulation (Ex.: \checkmark non-destructive imaging)

Advantages

- ✓ Tunability frequency range All diode lasers are phaselocked to the same master up to 1 GHz
- ✓ Sideband generation
- Fast beam extinction and power modulation
- laser Laser head power splitting with independent power control

